L Number	Hits	Search Text	DB	Time stamp
1	4	(("5756391") or ("6261908") or ("6297144") or	USPAT;	2004/06/23 07:19
		("6335250")).PN.	US-PGPUB	
2	1038	selectively with implant\$3 with (Si or silicon)	USPAT;	2004/06/23 07:28
2	4400707	Co or sohelf	US-PGPUB	2004/06/23 07:28
3	1126707	Co or cobalt	USPAT; US-PGPUB	2004/06/23 07:26
4	6	(selectively with implant\$3 with (Si or silicon)) with (Co or	USPAT;	2004/06/23 07:27
		cobalt)	US-PGPUB	
5	138946	@ad>20030110 or @rlad>20030110	USPAT;	2004/06/23 07:27
	_		US-PGPUB	
6	5	((selectively with implant\$3 with (Si or silicon)) with (Co or cobalt)) not (@ad>20030110 or @rlad>20030110)	USPAT; US-PGPUB	2004/06/23 07:27
7	3614	selectively and implant\$3 and (Si or silicon)	EPO; JPO;	2004/06/23 07:28
'	0014	Solodition and implanted and (or or onestry	DERWENT;	200 1100120 01120
			IBM_TDB	
8	5618586	Co or cobalt	EPO; JPO;	2004/06/23 07:28
			DERWENT;	
9	743	(selectively and implant\$3 and (Si or silicon)) and (Co or	IBM_TDB EPO; JPO;	2004/06/23 07:28
1	/ -3	cobalt)	DERWENT:	2004/00/20 07:20
			IBM_TDB	
10	1064880	semiconductor or "integrated circuit"	EPO; JPO;	2004/06/23 07:29
			DERWENT;	
11	561	((selectively and implant\$3 and (Si or silicon)) and (Co or	IBM_TDB EPO; JPO;	2004/06/23 07:30
	361	cobalt)) and (semiconductor or "integrated circuit")	DERWENT;	2004/00/23 07.30
		obstancy and (common audion or integration of our y	IBM TDB	
12	22606	silicide or silicidizing	EPO; JPO;	2004/06/23 07:30
			DERWENT;	
12	62	(//aclastively and implent\$3 and (\$i ar ailians)) and (\$Ca ar	IBM_TDB EPO; JPO;	2004/06/23 07:30
13	02	(((selectively and implant\$3 and (Si or silicon)) and (Co or cobalt)) and (semiconductor or "integrated circuit")) and	DERWENT;	2004/00/23 07.30
		(silicide or silicidizing)	IBM_TDB	
-	628	438/683.ccls.	USPAT;	2004/06/22 11:54
			US-PGPUB	0004/00/00 40 50
-	362	438/683.ccls. and (Co or cobalt)	USPAT; US-PGPUB	2004/06/22 10:58
_	357	(438/683.ccls. and (Co or cobalt)) not (@ad>20030110 or	USPAT;	2004/06/22 11:03
		@rlad>20030110)	US-PGPUB	
-	19170	implant\$3 with (Si or silicon)	USPAT;	2004/06/23 07:26
	400	(/400/000	US-PGPUB	2004/00/00 44.00
-	103	((438/683.ccls. and (Co or cobalt)) not (@ad>20030110 or @rlad>20030110)) and (implant\$3 with (Si or silicon))	USPAT; US-PGPUB	2004/06/22 11:03
_	490	438/682.ccls.	USPAT:	2004/06/22 11:55
			US-PGPUB	
-	355	(Co or cobalt) and 438/682.ccls.	USPAT;	2004/06/22 11:55
	210	 "high melting-point metal"	US-PGPUB USPAT;	2004/06/22 11:55
-	210	mgn metung-point metal	US-PGPUB	2007/00/22 11:00
-	1	438/682.ccls. and "high melting-point metal"	USPAT;	2004/06/22 11:55
			US-PGPUB	
-	346	((Co or cobalt) and 438/682.ccls.) not (@ad>20030110 or	USPAT;	2004/06/22 11:56
	314	@rlad>20030110) (((Co or cobalt) and 438/682.ccls.) not (@ad>20030110 or	US-PGPUB USPAT;	2004/06/22 11:57
	314	@rlad>20030110)) not (((438/683.ccls. and (Co or cobalt)) not	US-PGPUB	2007/00/22 11.0/
		(@ad>20030110 or @rlad>20030110)) and (implant\$3 with (Si		
		or silicon)))		
-	73	(implant\$3 with (Si or silicon)) and ((((Co or cobalt) and	USPAT;	2004/06/22 11:57
		438/682.ccls.) not (@ad>20030110 or @rlad>20030110)) not (((438/683.ccls. and (Co or cobalt)) not (@ad>20030110 or	US-PGPUB	
		@rlad>20030110)) and (implant\$3 with (Si or silicon))))		
-	1	("5940726").PN.	USPAT;	2004/06/23 07:19
			US-PGPUB	